SANGDEST MICROELECTRONICS

BAS16WS SURFACE MOUNT FAST SWITCHING DIODE

Technical Data Data Sheet N0585, Rev. -

Features

- High Conductance
- Fast Switching
- Surface Mount Package Ideally Suited for Automatic Insertion
- For General Purpose and Switching
- Plastic Material UL Recognition Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

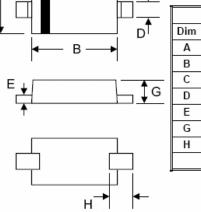
Mechanical Data

- Case: SOT-323, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 0.006 grams (approx.)
- Mounting Position: Any
- Marking: A6

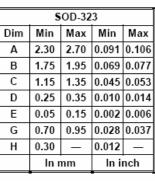
Maximum Ratings @TA=25°C unless otherwise specified

Characteristic	Symbol	BAS16WS	Unit
Non-Repetitive Peak Reverse Voltage	VRM	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	75	v
RMS Reverse Voltage	VR(RMS)	53	v
Forward Continuous Current (Note 1)	lfм	300	mA
Average Rectified Output Current (Note 1)	lo	150	mA
Non-Repetitive Peak Forward Surge Current @t = 1.0µs @t = 1.0s	IFSM	2.0 1.0	А
Power Dissipation (Note 1)	Pd	200	mW
Typical Thermal Resistance, Junction to Ambient Air (Note 1)	R⊕ JA	625	K/W
Operating and Storage Temperature Range	Tj, Tstg	-65 to +150	°C

Green Products



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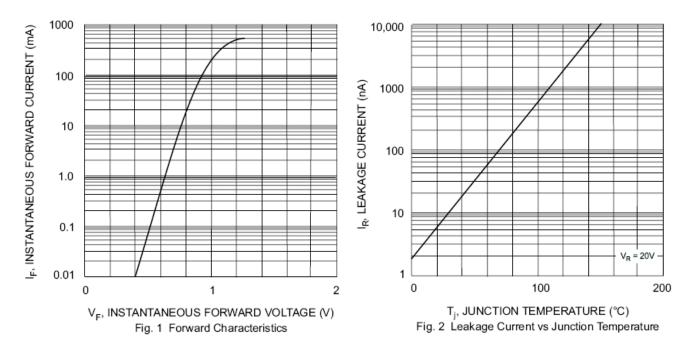
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Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic		Symbol	BAS16WS	Unit
Forward Voltage Drop	@ IF = 10mA	Vfm	0.855	V
Peak Reverse Leakage Current	@ Vr = 75V	IRM	1.0	μA
Junction Capacitance (VR = 0V DC, f = 1.0MHz)		Cj	2.0	pF
Reverse Recovery Time (Note 2)		trr	6.0	nS

Note: 1. Valid provided that terminals are kept at ambient temperature.

2. Measured with IF = IR = 10mA, IRR = $0.1 \times IR$, RL = 100Ω .





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